

PMEG3010CEJ

Data Sheet

Low VCEsat (BISS) transistors

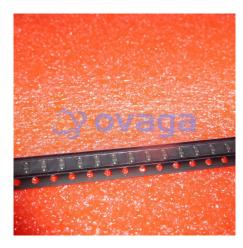
Manufacturers NXP Semiconductor

Package/Case SOD-323

Product Type Discrete Semiconductors

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for PMEG3010CEJ or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

PMEG3010CEJ is a high-performance Schottky diode manufactured by Nexperia. Here are some of its features:

Features

Maximum continuous forward current: 3 A

Reverse voltage: 100 V

Low forward voltage: 350 mV @ 1 A

Low leakage current: 5 µA @ 100 V

High reliability and ruggedness

AEC-Q101 qualified for automotive applications

Application

Power supply and DC-DC converters

LED lighting

Portable devices

Automotive electronics

Reverse polarity protection



Related Products



PMD3001D

NXP Semiconductor ST457



PMPB10XNE

NXP Semiconductor



PMF400UN

NXP Semiconductor SOT-323



PMGD400UN

NXP Semiconductor SOT-363



PMLL4448 NXP Semiconductor SOD-80C



NXP Semiconductor

PMZ370UNE



PMGD780SN

NXP Semiconductor



PMGD280UN

NXP Semiconductor